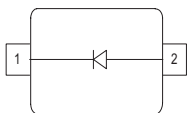
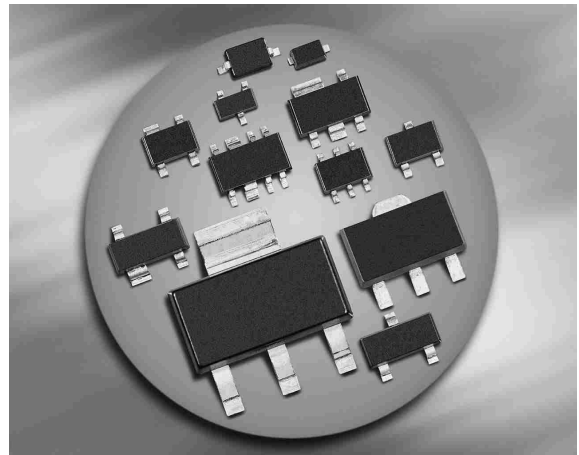


Silicon Tuning Diodes

- Excellent linearity
- High Q hyperabrupt tuning diode
- Low series resistance
- Designed for low tuning voltage operation for VCO's in mobile communications equipment
- Very low capacitance spread
- Pb-free (RoHS compliant) package



BBY55-02V
BBY55-02W
BBY55-03W



| Type | Package | Configuration | L_S (nH) | Marking |
|-----------|---------|---------------|------------|---------|
| BBY55-02V | SC79 | single | 0.6 | 7 |
| BBY55-02W | SCD80 | single | 0.6 | 77 |
| BBY55-03W | SOD323 | single | 1.8 | white 7 |

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

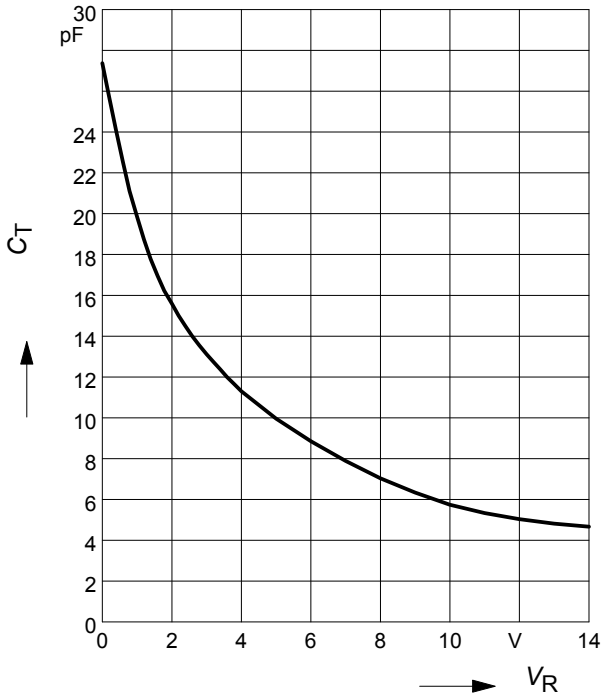
| Parameter | Symbol | Value | Unit |
|-----------------------------|-----------|-------------|------|
| Diode reverse voltage | V_R | 16 | V |
| Forward current | I_F | 20 | mA |
| Operating temperature range | T_{op} | -55 ... 150 | °C |
| Storage temperature | T_{stg} | -55 ... 150 | |

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|---|------------------|--------|------|------|----------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Reverse current | I_R | | | | nA |
| $V_R = 15\text{ V}$ | | - | - | 3 | |
| $V_R = 15\text{ V}, T_A = 85^\circ\text{C}$ | | - | - | 100 | |
| AC Characteristics | | | | | |
| Diode capacitance | C_T | | | | pF |
| $V_R = 1\text{ V}, f = 1\text{ MHz}$ | | 17.5 | 18.6 | 19.6 | |
| $V_R = 2\text{ V}, f = 1\text{ MHz}$ | | 14 | 15 | 16 | |
| $V_R = 3\text{ V}, f = 1\text{ MHz}$ | | 11.6 | 12.6 | 13.6 | |
| $V_R = 4\text{ V}, f = 1\text{ MHz}$ | | 10 | 11 | 12 | |
| $V_R = 10\text{ V}, f = 1\text{ MHz}$ | | 5.5 | 6 | 6.5 | |
| Capacitance ratio | C_{T2}/C_{T10} | 2 | 2.5 | 3 | |
| $V_R = 2\text{ V}, V_R = 10\text{ V}, f = 1\text{ MHz}$ | | | | | |
| Series resistance | r_S | - | 0.15 | 0.4 | Ω |
| $V_R = 5\text{ V}, f = 470\text{ MHz}$ | | | | | |

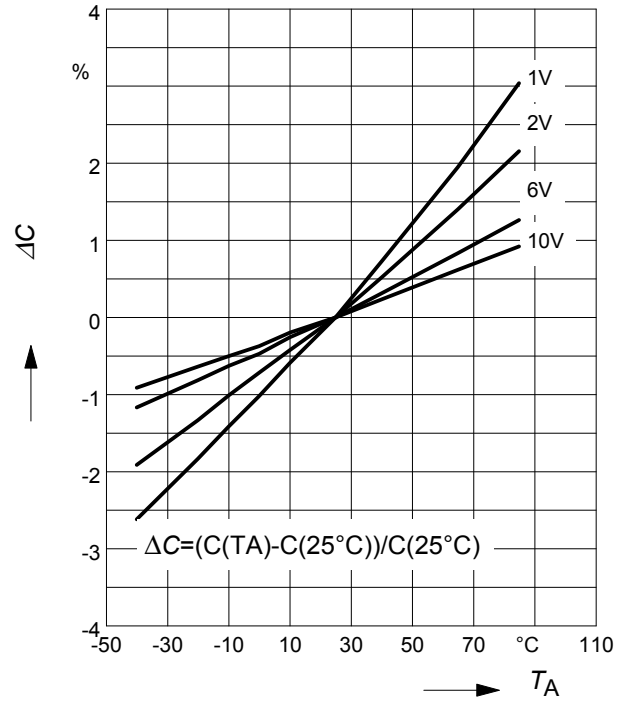
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$



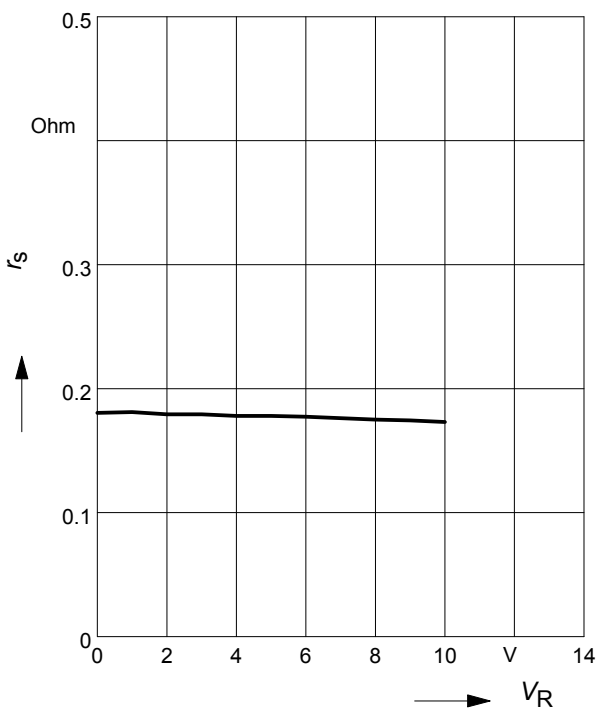
Capacitance change $\Delta C = f(T_A)$

$f = 1\text{MHz}$



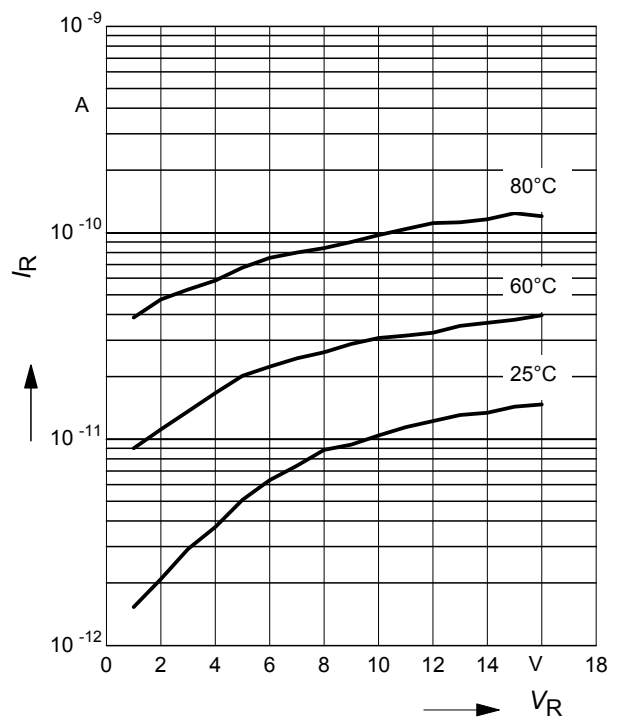
Series resistance $r_S = f(V_R)$

$f = 470\text{MHz}$

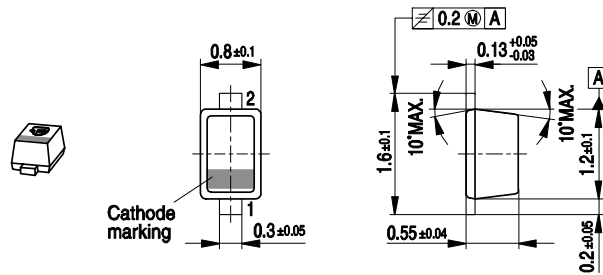


Reverse current $I_R = f(V_R)$

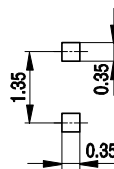
$T_A = \text{Parameter}$



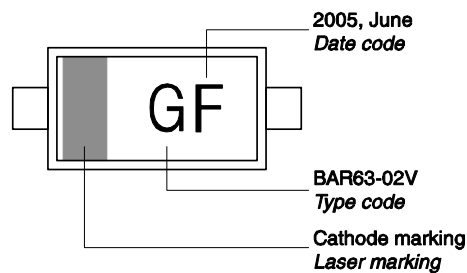
Package Outline



Foot Print

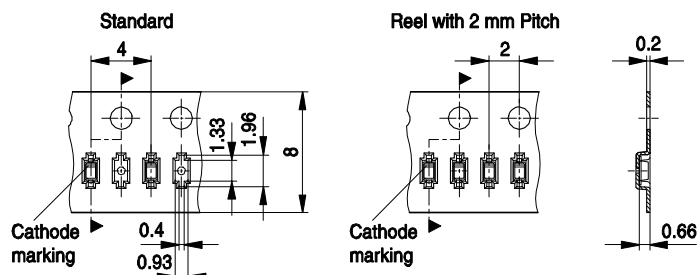


Marking Layout (Example)

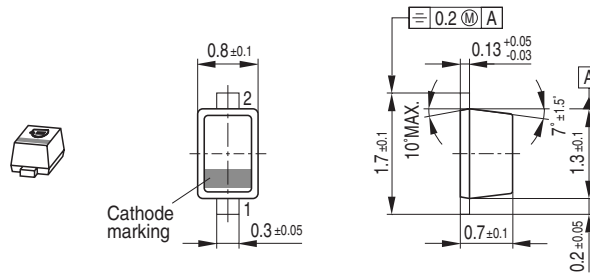


Standard Packing

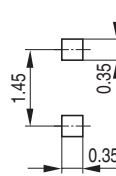
Reel \varnothing 180 mm = 3.000 Pieces/Reel
 Reel \varnothing 180 mm = 8.000 Pieces/Reel (2 mm Pitch)
 Reel \varnothing 330 mm = 10.000 Pieces/Reel



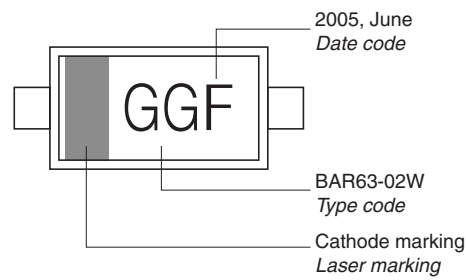
Package Outline



Foot Print

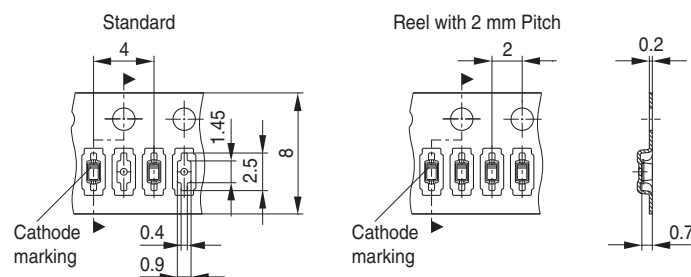


Marking Layout (Example)



Standard Packing

Reel \varnothing 180 mm = 3.000 Pieces/Reel
 Reel \varnothing 180 mm = 8.000 Pieces/Reel (2 mm Pitch)
 Reel \varnothing 330 mm = 10.000 Pieces/Reel

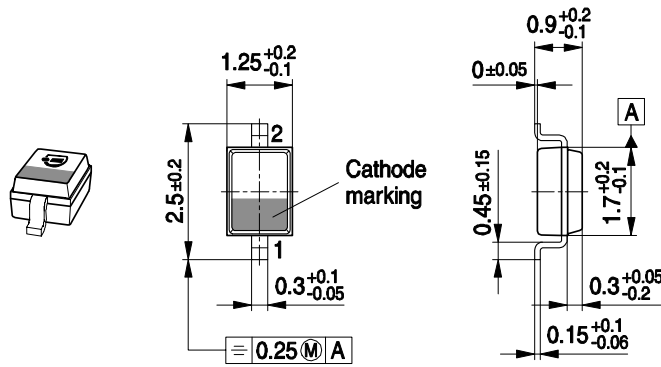


Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

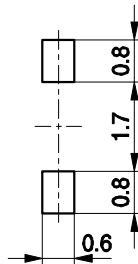
| Month | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 | 2013 | 2014 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| 01 | a | p | A | P | a | p | A | P | a | p | A | P |
| 02 | b | q | B | Q | b | q | B | Q | b | q | B | Q |
| 03 | c | r | C | R | c | r | C | R | c | r | C | R |
| 04 | d | s | D | S | d | s | D | S | d | s | D | S |
| 05 | e | t | E | T | e | t | E | T | e | t | E | T |
| 06 | f | u | F | U | f | u | F | U | f | u | F | U |
| 07 | g | v | G | V | g | v | G | V | g | v | G | V |
| 08 | h | x | H | X | h | x | H | X | h | x | H | X |
| 09 | j | y | J | Y | j | y | J | Y | j | y | J | Y |
| 10 | k | z | K | Z | k | z | K | Z | k | z | K | Z |
| 11 | l | 2 | L | 4 | l | 2 | L | 4 | l | 2 | L | 4 |
| 12 | n | 3 | N | 5 | n | 3 | N | 5 | n | 3 | N | 5 |

1) New Marking Layout for SC75, implemented at October 2005.

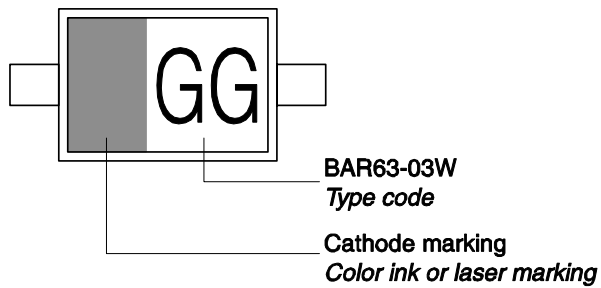
Package Outline



Foot Print

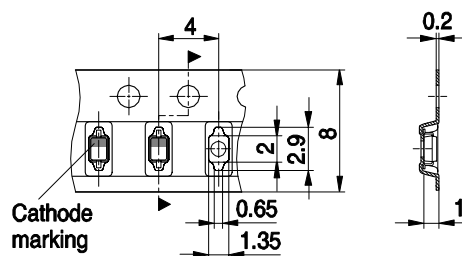


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø330 mm = 10.000 Pieces/Reel



Edition 2009-11-16

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Infineon Technologies AG
81726 Munich, Germany**

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